

# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.42 \text{ V}$  at  $I_F = 5 \text{ A}$ 

# TMBS® ITO-220AB VF40100G PIN 1 OPPIN 2

PRIMARY CHARACTERISTICS				
IF <sub>(AV)</sub>	2 x 20 A			
V <sub>RRM</sub>	100 V			
I <sub>FSM</sub>	200 A			
V <sub>F</sub> at I <sub>F</sub> = 20 A	0.67 V			
T <sub>J</sub> max.	150 °C			

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

• Low thermal resistance

ROHS COMPLIANT HALOGEN FREE

- Solder dip 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

#### **MECHANICALDATA**

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VF40100G	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	100	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	40	۸	
	per diode		20	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	200	Α	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Isolation voltage from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500	V	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 40 to + 150	°C	



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Breakdown voltage	I <sub>R</sub> = 1 mA	T <sub>A</sub> = 25 °C	$V_{BR}$	100 min.	-		
Instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub>	0.49	-	V	
	I <sub>F</sub> = 10 A			0.59	-		
	I <sub>F</sub> = 20 A			0.75	0.81		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.42	-		
	I <sub>F</sub> = 10 A			0.54	-		
	I <sub>F</sub> = 20 A	]		0.67	0.73		
Rverse current per diode (2)	V 70.V	T <sub>A</sub> = 25 °C		12	-	μΑ	
	V <sub>R</sub> = 70 V	T <sub>A</sub> = 125 °C	I <sub>R</sub>	8	-	mA	
	V 100 V	T <sub>A</sub> = 25 °C		55	500	μA	
	V <sub>R</sub> = 100 V	T <sub>A</sub> = 125 °C		21	35	mA	

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VF40100G	UNIT	
Typical thermal resistance per diode	$R_{ hetaJC}$	5.0	°C/W	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VF40100G-M3/4W	1.75	4W	50/tube	Tube

### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

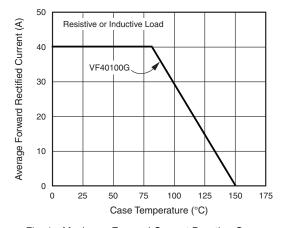


Fig. 1 - Maximum Forward Current Derating Curve

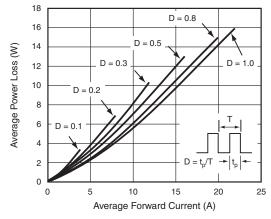


Fig. 2 - Forward Power Loss Characteristics



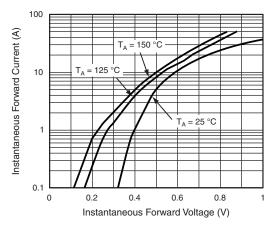


Fig. 3 - Typical Instantaneous Forward Characteristics

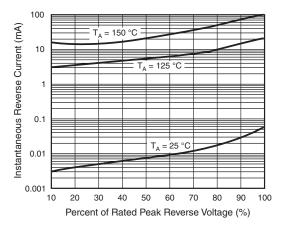


Fig. 4 - Typical Reverse Characteristics

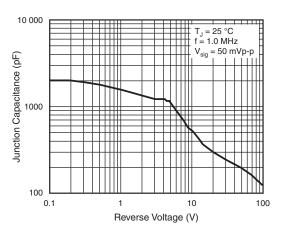


Fig. 5 - Typical Junction Capacitance

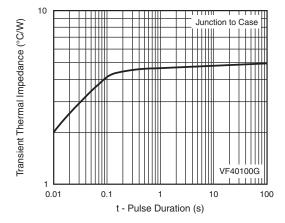
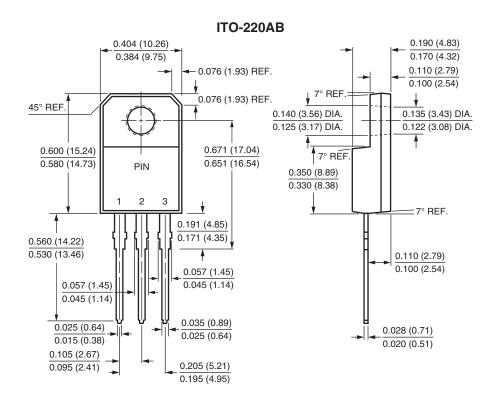


Fig. 6 - Typical Transient Thermal Impedance



#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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Revision: 02-Oct-12 Document Number: 91000